NSN 5961-00-076-6123 Thyristor Semiconductor Device - Page 1 of 1



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nclosure Material:
Metal
Overall Length:
Between 0.874 inches and 1.030 inches
Mounting Facility Quantity:
1
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.040 inches and 1.060 inches
Гhread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
300.0 breakover voltage, dc
Current Rating Per Characteristic:
55.00 amperes drain current
Power Rating Per Characteristic:
500.00 milliwatts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
125.0 degrees celsius junction
Γhread Series Designator:
Jnf
Ferminal Type And Quantity:
2 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Jnit Of Measure:
-
Demilitarization:
No
Filg:
A110a0